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Unit: mm

0.22^{+0.10} (0.13 M)

AN48830B

Low current consumption, high sensitivity CMOS Hall IC

Operate by the value of magnetic flux density, regardless of polarity

Overview

The AN48830B is a Hall IC (a magnetic sensor) which has 2 times or more sensitivity and a low current consumption of about one three-hundredth compared with our conventional one.

In this Hall IC, a Hall element, a offset cancel circuit, an amplifier circuit, a sample and hold circuit, a Schmidt circuit, and output stage FET are integrated on a single chip housed in a small package by IC technique.

■ Features

- Either North nor South magnetic pole can be selected *
- High sensitivity (6 mT max.) due to offset cancel circuit and a new sample and hold circuit
- Small current by using intermittent action (Average supply current: 3.5 μA typ.)
- Small package (SMD)
- CMOS inverter output (output form logic)

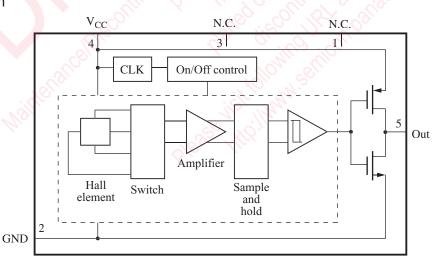
Applications

• Flip type cellular phone, digital video camera

SMINI-5DA (Lead-free package) Note) *: S Magnetic flux density AN48830B H Conventional model H Conventional model H

□0.10 Seating plane

■ Block Diagram



■ Pin Descriptions

Pin No.	Symbol	Description	Pin No.	Symbol	Description
1	N.C.	_	4	V_{CC}	Power supply
2	GND	Ground	5	Out	Output
3	N.C.	_			

■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage	V _{CC}	5	V
Output voltage	V _{OUT}	5	V
Supply current	I_{CC}	5	mA
Output current	I _{OUT}	15	mA
Power dissipation *1,*2	P_{D}	60	mW
Operating ambient temperature *1	T _{opr}	-25 to +75	°C
Storage temperature *1	T _{stg}	-55 to +125	°C

Note) *1: Except for the power dissipation, operating ambient temperature and storage temperature, all ratings are for T_a = 25°C.

■ Recommended Operating Range

Parameter	Symbol	Range	Unit		
Supply voltage	V _{CC}	2.5 to 3.5	V		

■ Electrical Characteristics $T_a = 25$ °C ± 2 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Operating magnetic flux density 1	B _{H-LS}	$V_{CC} = 3 V$	_	_	6	mT
Operating magnetic flux density 2 *1	B _{H-LN}	$V_{CC} = 3 V$	-6	_	_	mT
Operating magnetic flux density 3 *2	$\mathrm{B}_{\mathrm{L ext{-}HS}}$	$V_{CC} = 3 V$	0.5	_	. 4.	mT
Operating magnetic flux density 4 *2	B _{L-HN}	$V_{CC} = 3 V$	_		-0.5	mT
Output voltage 1	V _{OLS}	$V_{CC} = 3 \text{ V, } I_O = 2 \text{ mA, B} = 6.0 \text{ mT}$	85_	0.1	0.3	V
Output voltage 2	V _{OLN}	$V_{CC} = 3 \text{ V, } I_O = 2 \text{ mA, } B = -6.0 \text{ mT}$	_	0.1	0.3	V
Output voltage 3	V _{OHS}	$V_{CC} = 3 \text{ V, } I_O = -2 \text{ mA, B} = 0.5 \text{ mT}$	2.7	2.9	_	V
Output voltage 4	V _{OHN}	$V_{CC} = 3 \text{ V, } I_O = -2 \text{ mA, B} = -0.5 \text{ mT}$	2.7	2.9	_	V
Supply current 1 *3	I _{CCAVE}	$V_{CC} = 3 \text{ V}$		3.5	7.0	μΑ

Note) *1: Symbol B_{H-LS}, B_{H-LN} stands for the operating magnetic flux density where its output level varies from high to low.

Design reference data

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Hysteresis width 1	BWS	$V_{CC} = 3 V$	_	1.2	_	mT
Hysteresis width 2	BWN	$V_{CC} = 3 V$	_	1.2	_	mT
Supply current 2	I_{CCON}	$V_{CC} = 3 V$	_	1.4	_	mA
Supply current 3	$I_{CC_{OFF}}$	$V_{CC} = 3 V$	_	2	_	μА
Operating time	t _{ON}	$V_{CC} = 3 V$	_	20	_	μs
Stop time	t _{OFF}	$V_{CC} = 3 V$	_	20.5	_	ms

Note) It will operate normally in approximately 41 ms after power on.

2 SPC00017AEB

^{*2:}T_a = 75°C. For the independent IC without a heat sink. Please use within the range of power dissipation, refering to P_D — T_a curve.

^{*2:}Symbol B_{L-HS}, B_{L-HN} stands for the operating magnetic flux density where its output level varies from low to high.

 $^{*3:} I_{CC_{AVE}} = \{I_{CC_{ON}} \times t_{ON} + I_{CC_{OFF}} \times t_{OFF}\} / \{t_{ON} + t_{OFF}\}$

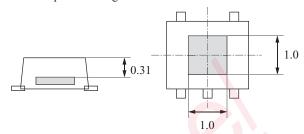
Panasonic

■ Technical Data

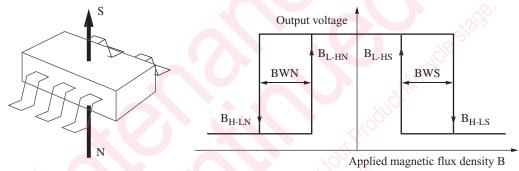
• Position of a Hall element (unit in mm)

Distance from a package surface to sensor part: 0.39 mm (reference value)

A Hall element is placed on the shaded part in the figure.



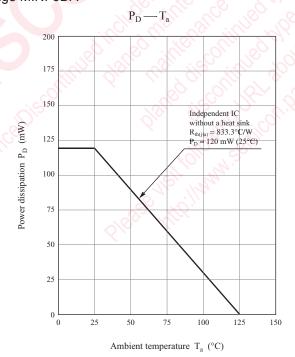
• Magneto-electro conversion characteristics



Direction of applied magnetic field

Operating magnetic flux density

Power dissipation of package MINI-5DA

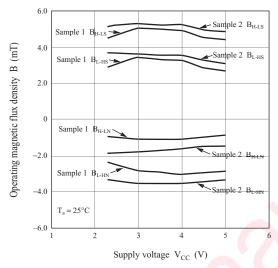


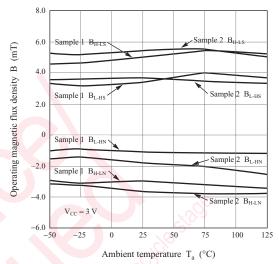
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■ Technical Data (continued)

• Main characterisitcs

Operating magnetic flux density — Supply voltageOperating magnetic flux density — Ambient temperature

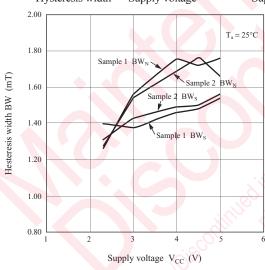


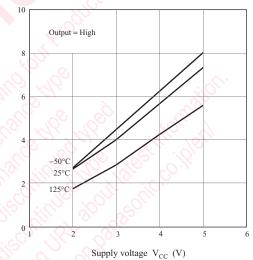


Hysteresis width — Supply voltage

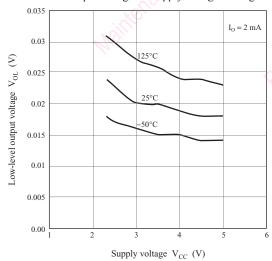
Supply current — Supply voltage

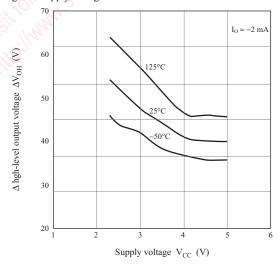
Supply current I_{CC} (µA)





Low-level output voltage — Supply voltage Δ high-level output voltage — Supply voltage





4 SPC00017AEB

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